

## HTK1A60/KTK1A80 4 Quadrants Sensitive TRIAC

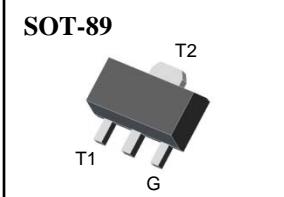
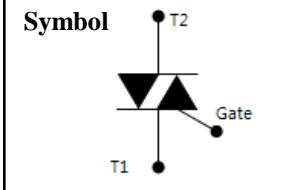
### FEATURES

- Repetitive Peak Off-State Voltage : 600V/800V
- R.M.S On-State Current ( $I_{T(RMS)} = 1\text{ A}$ )
- Sensitive Gate Trigger Current
  - 5[mA] of IGT at I, II and III Quadrants.
  - 12[mA] of IGT at IV Quadrant.

### Applications

AC power or phase control through low output current of MCU or IC such like Heater, Solenoid valve control, etc.

|                                     |
|-------------------------------------|
| $V_{DRM} = 600\text{V}/800\text{V}$ |
| $I_{T(RMS)} = 1\text{ A}$           |
| $I_{TSM} = 13\text{ A}$             |
| $I_{GT} = 5\text{mA}/12\text{mA}$   |



### General Description

Semihow's sensitive TRIAC product is a glass passivated device, has a low gate trigger current, high stability in gate trigger current to variation of operating temperature and high off state voltage. It is generally suitable for power and phase control in ac application.

### Absolute Maximum Ratings ( $T_J=25^\circ\text{C}$ unless otherwise specified)

| Symbol       | Parameter                              | Conditions   | Ratings           |         | Unit                 |
|--------------|--|--|-------------------|---------|----------------------|
|              |  |  | HTK1A60           | HTK1A80 |                      |
| $V_{DRM}$    | Repetitive Peak Off-State Voltage      | Sine wave, 50/60Hz, Gate open                                | 600               | 800     | V                    |
| $V_{RRM}$    | Repetitive Peak Reverse Voltage        |  | 600               | 800     | V                    |
| $I_{T(AV)}$  | Average On-State Current               | Full sine wave, $T_C = 72^\circ\text{C}$                     | 0.9               |         | A                    |
| $I_{T(RMS)}$ | R.M.S. On-State Current                |  | 1                 |         | A                    |
| $I_{TSM}$    | Surge On-State Current                 | $\frac{1}{2}$ cycle, 50Hz/60Hz, Sine wave, Non repetitive    | 12/13             |         | A                    |
| $I^2t$       | Fusing Current                         | $t = 10\text{ms}$  | 0.7               |         | $\text{A}^2\text{S}$ |
| $P_{GM}$     | Forward Peak Gate Power Dissipation    | $T_J = 125^\circ\text{C}$                                    | 2                 |         | W                    |
| $P_{G(AV)}$  | Forward Average Gate Power Dissipation | $T_J = 125^\circ\text{C}$ , over any 20ms                    | 0.2               |         | W                    |
| $I_{FGM}$    | Forward Peak Gate Current              | $T_J = 125^\circ\text{C}$ , pulse width $\leq 20\mu\text{s}$ | 0.5               |         | A                    |
| $V_{RGM}$    | Reverse Peak Gate Voltage              | $T_J = 125^\circ\text{C}$ , pulse width $\leq 20\mu\text{s}$ | 6                 |         | V                    |
| $T_J$        | Operating Junction Temperature         |  | $-40\text{~}+125$ |         | $^\circ\text{C}$     |
| $T_{STG}$    | Storage Temperature                    |  | $-40\text{~}+150$ |         | $^\circ\text{C}$     |

**Electrical Characteristics** ( $T_J=25^\circ\text{C}$  unless otherwise specified)

| Symbol    | Parameter                                  | Conditions   | Min                     | Typ | Max | Unit  |
|-----------|--|--|-------------------------|-----|-----|-------|
| $I_{DRM}$ | Repetitive Peak Off-State Current          | $V_D = V_{DRM}$  | $T_J=25^\circ\text{C}$  | -   | -   | 50 uA |
|           |  |  | $T_J=125^\circ\text{C}$ | -   | -   | 5 mA  |
| $I_{RRM}$ | Repetitive Peak Reverse Current            | $V_D = V_{DRM}$  | $T_J=25^\circ\text{C}$  | -   | -   | 50 uA |
|           |  |  | $T_J=125^\circ\text{C}$ | -   | -   | 5 mA  |
| $I_{GT}$  | Gate Trigger Current                       | $V_D = 12\text{V}$ , $R_L=330\Omega$                           | 1+, 1-, 3-              | -   | -   | 5 mA  |
|           |  |  | 3+                      | -   | -   | 12 mA |
| $V_{GT}$  | Gate Trigger Voltage                       | $V_D = 12\text{V}$ , $R_L=330\Omega$                           | 1+, 1-, 3-              | -   | -   | 1.5 V |
|           |  |  | 3+                      | -   | -   | 2.0 V |
| $V_{GD}$  | Non-Trigger Gate Voltage <sup>1</sup>      | $V_D = 12\text{V}$ , $R_L=330\Omega$ , $T_J=125^\circ\text{C}$ | 0.2                     | -   | -   | V     |
| $V_{TM}$  | Peak On-State Voltage                      | $I_T = 1.4\text{A}$ , $I_G = 20\text{mA}$                      | -                       | 1.2 | 1.6 | V     |
| $dv/dt$   | Critical Rate of Rise of Off-State Voltage | $V_D = 2/3 V_{DRM}$ , $T_J=125^\circ\text{C}$                  | 10                      | -   | -   | V/us  |
| $I_H$     | Holding current                            | $I_T = 0.2\text{A}$  | -                       | -   | 5   | mA    |

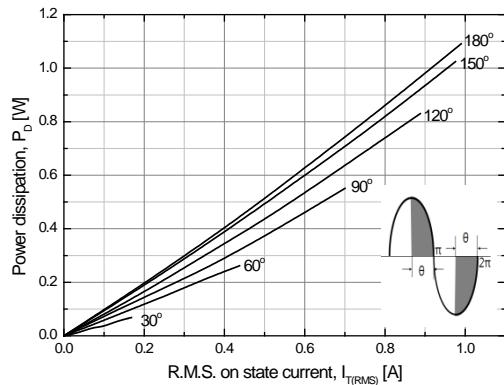
**Notes :**

1. Pulse Width
- $\leq 1.0\text{ms}$
- , Duty Cycle
- $\leq 1\%$

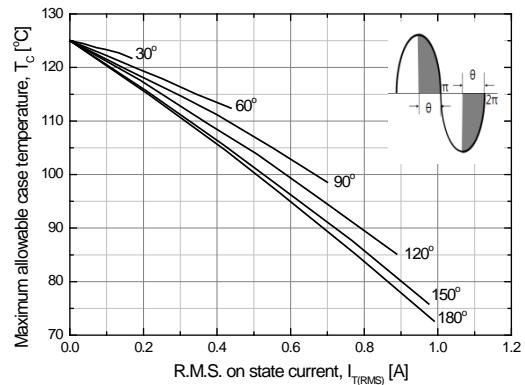
**Thermal Characteristics**

| Symbol          | Parameter          | Conditions          | Min | Typ | Max | Unit |
|-----------------|--------------------|---------------------|-----|-----|-----|------|
| $R_{\theta JC}$ | Thermal Resistance | Junction to Case    |     |     | 48  | °C/W |
| $R_{\theta JA}$ | Thermal Resistance | Junction to Ambient |     |     | 150 | °C/W |

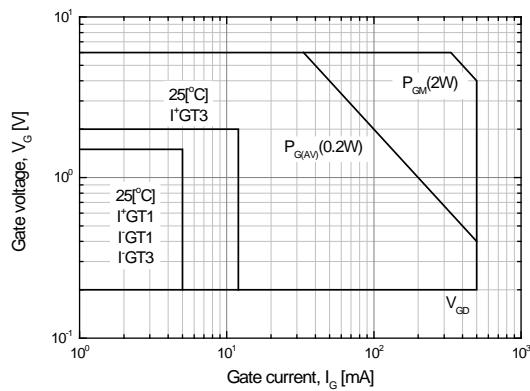
## Typical Characteristics



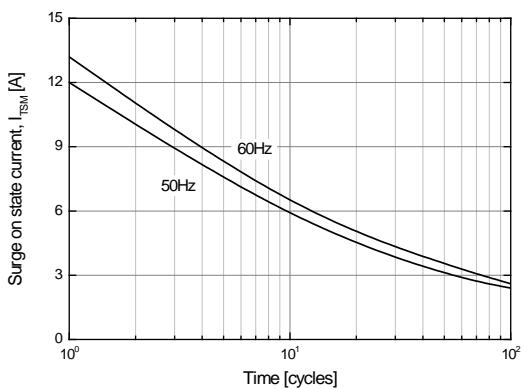
**Fig 1. R.M.S. current vs. Power dissipation**



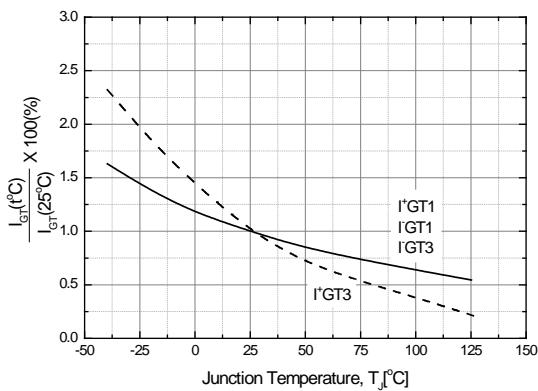
**Fig 2. R.M.S. current vs. Case temperature**



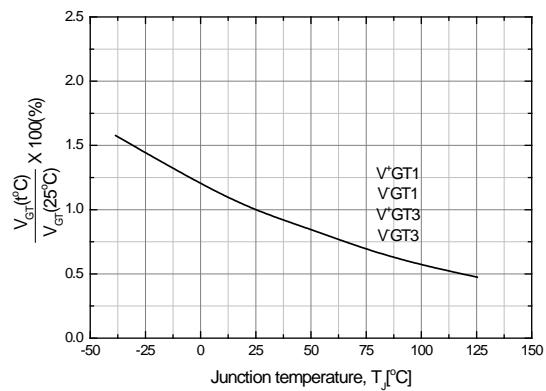
**Fig 3. Gate power characteristics**



**Fig 4. Surge on state current rating  
(Non-repetitive)**

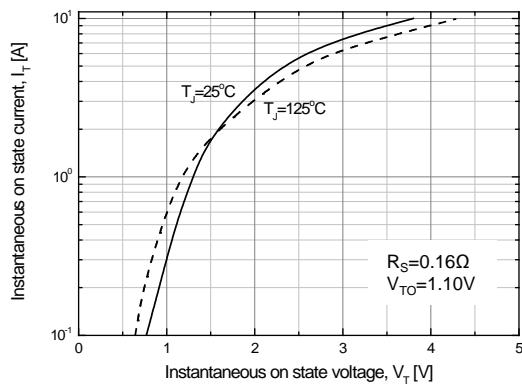


**Fig 5. Gate trigger current vs.  
junction temperature**

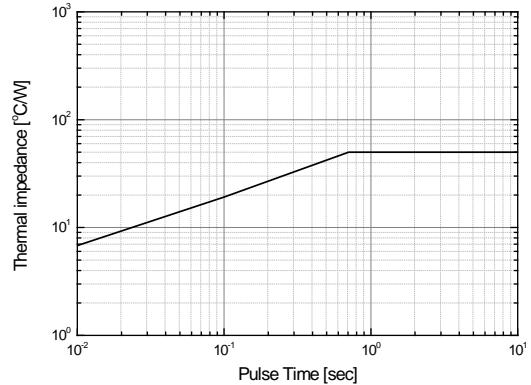


**Fig 6. Gate trigger voltage vs.  
junction temperature**

## Typical Characteristics

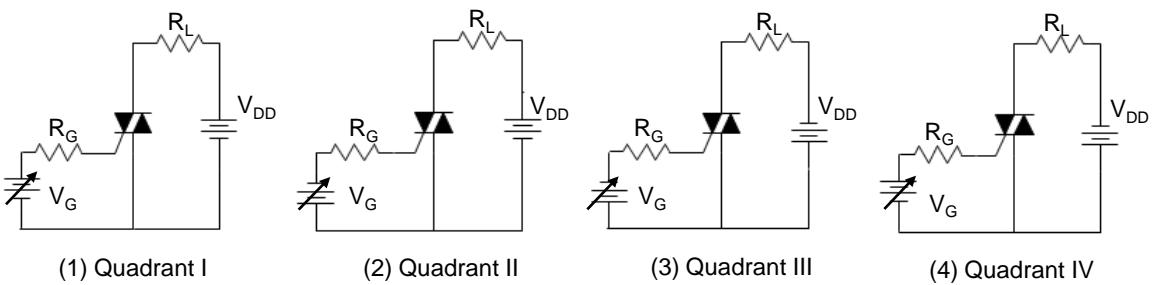


**Fig 7. Instantaneous on state current vs. Instantaneous on state voltage**



**Fig 8. Thermal Impedance vs. pulse time**

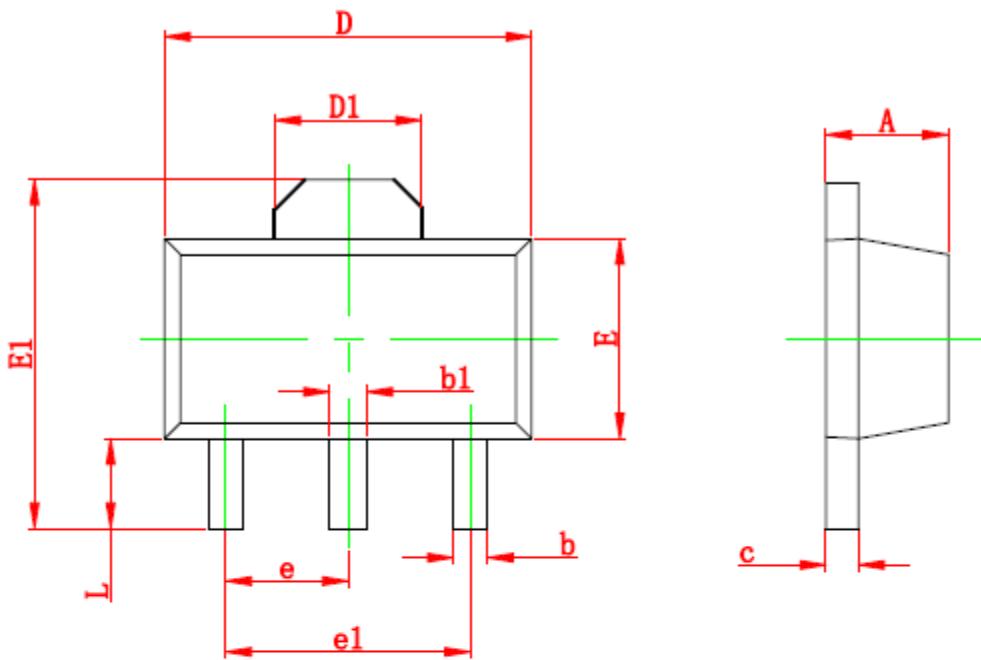
### Measurement of gate trigger current



Note. Whole parameter and test condition can not be over absolute maximum ratings in this datasheet.

## Package Dimension

SOT-89-3L



| Symbol | Dimensions In Millimeters |       | Dimensions In Inches |       |
|--------|---------------------------|-------|----------------------|-------|
|        | Min                       | Max   | Min                  | Max   |
| A      | 1.400                     | 1.600 | 0.055                | 0.063 |
| b      | 0.320                     | 0.520 | 0.013                | 0.020 |
| b1     | 0.400                     | 0.580 | 0.016                | 0.023 |
| c      | 0.350                     | 0.440 | 0.014                | 0.017 |
| D      | 4.400                     | 4.600 | 0.173                | 0.181 |
| D1     | 1.550 REF.                |       | 0.061 REF.           |       |
| E      | 2.300                     | 2.600 | 0.091                | 0.102 |
| E1     | 3.940                     | 4.250 | 0.155                | 0.167 |
| e      | 1.500 TYP.                |       | 0.060 TYP.           |       |
| e1     | 3.000 TYP.                |       | 0.118 TYP.           |       |
| L      | 0.900                     | 1.200 | 0.035                | 0.047 |